NSN 5962-01-346-1906

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View Online at https://aerobasegroup.com/nsn/5962-01-346-1906

Overall Length:

Between 1.235 inches and 1.280 inches

Overall Height:

Between 0.265 inches and 0.360 inches

Body Length:

Between 1.235 inches and 1.280 inches

Body Width:

Between 0.280 inches and 0.310 inches

Body Height:

Between 0.080 inches and 0.185 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Electrostatic sensitive and bipolar and programmable and 3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Case Outline Source And Designator:

D-9 mil-m-38510

Current Rating Per Characteristic:

188.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

Err-060 and err-060

Time Rating Per Chacteristic:

35.00 nanoseconds delay

Memory Device Type:

Prom

Unpackaged Unit Weight:

6.5 grams

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type Ar	nd Quantity:
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24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0